



SBR160S23

# 1A SBR<sup>®</sup> SUPER BARRIER RECTIFIER

#### **Features**

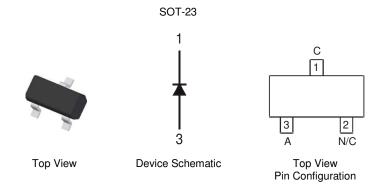
- Low Forward Voltage Drop
- Low Reverse Leakage
- Excellent High Temperature Stability
- Patented Super Barrier Rectifier Technology
- · Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- Totally Lead- Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating).

Solderable per MIL-STD-202, Method 208 @3

- Polarity: See Diagram
- Weight: 0.008 grams (Approximate)



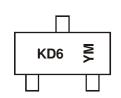
### Ordering Information (Note 4)

Part Number	Case	Packaging
SBR160S23-7	SOT-23	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



SOT-23

KD6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Year	2010	20	11	2012	2013	201	4	2015	2016	20	017	2018
Code	Χ	Y	′	Z	Α	В		С	D		E	F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$		
Working Peak Reverse Voltage	$V_{RWM}$	60	V
DC Blocking Voltage	$V_{RM}$		
Average Rectified Output Current	I <sub>O</sub>	900	mA
Average Peak Forward Current; D.C. = 50%	I <sub>FAV</sub>	1,600	mA
Non-Repetitive Peak Forward Surge Current	I	15	۸
8.3ms Single Half Sine-Wave Superimposed on Rated Load	IFSM	13	А

#### **Thermal Characteristics**

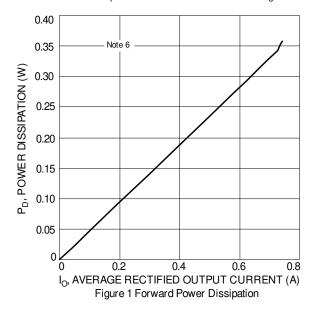
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	500	mW
Typical Thermal Resistance Thermal Resistance Junction to Ambient Air (Note 5) Thermal Resistance Junction to Ambient Air (Note 6)	$egin{array}{c} R_{ heta JA} \ R_{ heta JA} \end{array}$	300 250	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

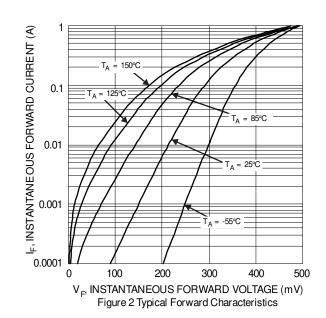
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	$V_{R}$	60	-	-	V	$I_R = 1mA$
	V <sub>F</sub>	-	-	470		I <sub>F</sub> = 500mA
Forward Voltage (Per Diode)			-	530 600	mV	I <sub>F</sub> = 750mA
			-	740		$I_F = 1000 \text{mA}$ $I_F = 1500 \text{mA}$
Leakage Current (Note 7)	I <sub>R</sub>	-	-	100	μΑ	$V_R = 45V, T_J = +25^{\circ}C$
Total Capacitance	Ст	-	19	-	pF	$V_R = 25V$ , $f = 1MHz$
Reverse Recovery Time	t <sub>rr</sub>	-	16	-	ns	$I_F = I_R = 10$ mA, $IRR = 0.1 \times I_R$ $R_L = 100\Omega$

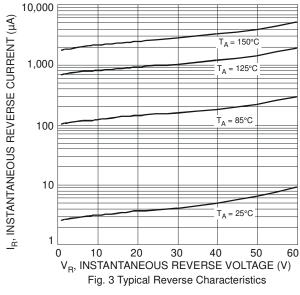
Notes:

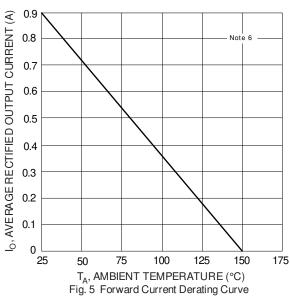
- 5. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com.
- 6. Part mounted on 1 inch sq. 2oz copper pad.
- 7. Short duration pulse test used to minimize self-heating effect.

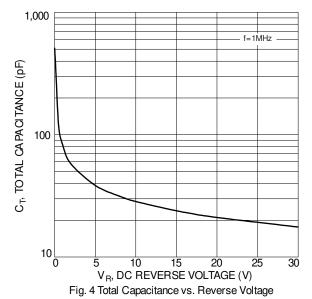


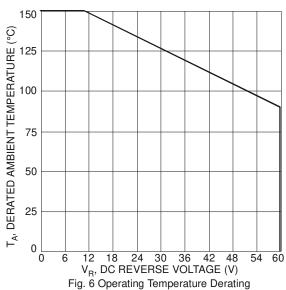






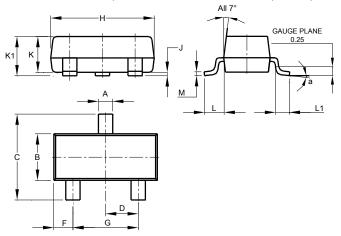






## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

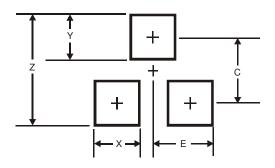


SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
C	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
7	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
M	0.085	0.150	0.110					
а	8°							
All	All Dimensions in mm							



#### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35

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